



晶体管光耦 Photo Transistor

4N25

Product Data Sheet

AOTE DCC
RELEASE

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概述 Description

4N25 是一款由发光二极管和一个光电晶体管组成的光电耦合器。六引脚封装（DIP6、SMD6）。
The 4N25 is a photoelectric coupler composed of light-emitting diode and phototransistor. It is packaged in a 6-pin package at DIP、SMD.

特性 Features

- 电流转换比(CTR)范围: $\geq 20\%$ ($I_F = 10\text{mA}$, $V_{CE} = 10\text{V}$, $T_a = 25^\circ\text{C}$)
Current transfer ratio: $\geq 20\%$ ($I_F = 10\text{mA}$, $V_{CE} = 10\text{V}$, $T_a = 25^\circ\text{C}$)
- 输入-输出隔离电压 ($V_{ISO} = 5000 \text{ Vrms}$)
High isolation voltage between input and output ($V_{ISO} = 5000 \text{ Vrms}$)
- 输入-输出隔离电阻 (典型值 $R_{iso} = 10^{11}\Omega$)
Input-output isolation voltage resistance ($R_{iso} = 10^{11}\Omega$)
- 工作温度: $-55^\circ\text{C} \sim 100^\circ\text{C}$
Operating Temperature: $-55^\circ\text{C} \sim 100^\circ\text{C}$
- 符合加强绝缘标准
Meet reinforced insulation standards
- 符合安规标准: UL 1577, VDE DIN EN60747-5-5 (VDE 0884-5), CQC11-471543-2022
Meet safety standard approval: UL 1577, VDE DIN EN60747-5-5 (VDE 0884-5), CQC11-471543-2022

应用 Applications

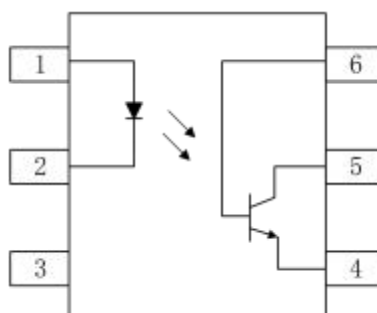
- 电源调节器
Power regulator
- 数字逻辑输入
Digital logic input
- 微处理器输入
Microprocessor input

封装和原理图 Package and Schematic Diagram



DIP6

SMD6



Pin Configuration

1. Anode
2. Cathode
3. NC
4. Emitter
5. Collector
6. Base

印字信息 Marking Information

- 印字中 “” 为奥特品牌 LOGO
“” denotes LOGO
- 印字中的 “XX” 代表产品分档： 25, 26, 27,28,35,36,37,38
“XX” denotes the classification： 25, 26, 27,28,35,36,37,38
- 印字中 “Y” 代表年份； A(2018),B(2019),C(2020)
“Y” denotes YEAR： A(2018), B(2019), C(2020)
- 印字中 “WW” 代表周号
“WW” denotes Week’ s number
- 印字中 “E” 代表产品版本号
“E” denotes product versions
- 印字中的 “H” 代表无卤
“H” denotes Halogen-free



绝缘和安规信息 Insulation and Safety related specifications

项目 Item	符号 Symbol	数值 Value	单位 Unit	备注 Remark
爬电距离 Creepage Distance	L	> 7.0	mm	从输入端到输出端，沿本体最短距离路径 Measured from input terminals to output terminals, shortest distance path along body
电气间隙 Clearance Distance	L	> 7.0	mm	从输入端到输出端，通过空气的最短距离 Measured from input terminals to output terminals, shortest distance through air
绝缘距离 Insulation Thickness	DTI	> 0.4	mm	发射器和探测器之间的绝缘厚度 Insulation thickness between emitter and detector
峰值隔离电压 Peak Isolation Voltage	V _{IORM}	1500	V _{peak}	DIN/EN/IEC EN60747-5-5
瞬态隔离电压 Transient isolation voltage	V _{IOTM}	7000	V _{peak}	DIN/EN/IEC EN60747-5-5
隔离电压 Isolation Voltage	V _{iso}	> 5000	V _{rms}	For 1 min, RH < 60%

极限参数 Absolute Maximum Ratings (Ta = 25°C)

参数 Parameter		符号 Symbol	额定值 Rating	单位 Unit
发射端 Input	正向电流 Forward Current	I _F	60	mA
	峰值正向电流(1us, 脉冲) Peak forward current (1us, pulse)	I _{FP}	1000	mA
	反向电压 Reverse Voltage	V _R	6	V
	功耗 Power Dissipation	P _D	100	mW
接收端 output	集电极功耗 Collector Power Dissipation	P _C	300	mW
	集电极电流 Collector Current	I _C	100	mA
	集电极-基极电压 Collector-Base Voltage	V _{CBO}	70	V
	集电极-发射极电压 Collector-Emitter Voltage	V _{CEO}	30	V
	发射极-集电压 Emitter - Collector Voltage	V _{ECO}	7	V
总功耗 Total Power Dissipation	P _{tot}	350	mW	
输入输出瞬态耐受电压 Input-output isolation voltage	V _{iso}	5000	V _{rms}	
工作温度 Operating Temperature	T _{opr}	-55 ~ +100	°C	
存储温度 Storage Temperature	T _{stg}	-55 ~ +150	°C	
焊接温度 Soldering Temperature	T _{sol}	260	°C	

产品特性参数 Electro-optical Characteristics (Ta = 25°C)

参数 Parameter		符号 Symbol	条件 Condition	最小 Min.	典型 Typ.	最大 Max.	单位 Unit	
发射端 Input	正向电压 Forward Voltage	V_F	$I_F=10\text{mA}$	-	1.2	1.5	V	
	反向电流 Reverse Current	I_R	$V_R=3\text{V}$	-	-	10	μA	
	输入电容 Terminal Capacitance	C_t	$V=0, F=1\text{KHz}$	-	50	-	pF	
接收端 Output	集电极暗电流 Collector Dark Current	I_{CEO}	$V_{CE}=10\text{V}$	-	-	50	nA	
	集电极-基极击穿电压 Collector-Base Breakdown Voltage	BV_{CBO}	$I_B=0.1\text{mA}, I_F=0$	70	-	-	V	
	集电极-发射极击穿电压 Collector-Emitter Breakdown Voltage	BV_{CEO}	$I_C=0.1\text{mA}, I_F=0$	30	-	-	V	
	发射极-集电极击穿电压 Emitter-Collector Breakdown Voltage	BV_{ECO}	$I_E=0.01\text{mA}, I_F=0$	7	-	-	V	
传输特性 Transfer Characteristics	电流传输比 Current Transfer Ratio	4N25、4N26、4N38	CTR^*	$I_F=10\text{mA}, V_{CE}=10\text{V}$	20	-	-	%
		4N27、4N28			10	-	-	%
		4N35、4N36、4N37			100	-	-	%
	集电极-发射极饱和压降 Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_F=50\text{mA}, I_C=2\text{mA}$	-	-	0.3	V	
	隔离电阻 Isolation Resistance	R_{ISO}	DC=500V 40 ~60%R.H.	5×10^{10}	1×10^{11}	-	Ω	
	隔离电容 Isolation capacitance	C_{ISO}	$V=0, F=1\text{MHz}$	-	1	2.5	pF	
	上升时间 Rise Time	T_r	$V_{CE}=10\text{V}, I_C=2\text{mA},$ $R_L=100\Omega$	-	4	-	μs	
下降时间 Fall Time	T_f	-		3	-	μs		

 注*：电流传输比= $I_C/I_F \times 100\%$ 。

 Note*：CTR= $I_C/I_F \times 100\%$ 。

典型光电特性曲线 Typical Electro-Optical Characteristics Curves

Fig.1 Relative Current Transfer Ratio vs. Forward Current

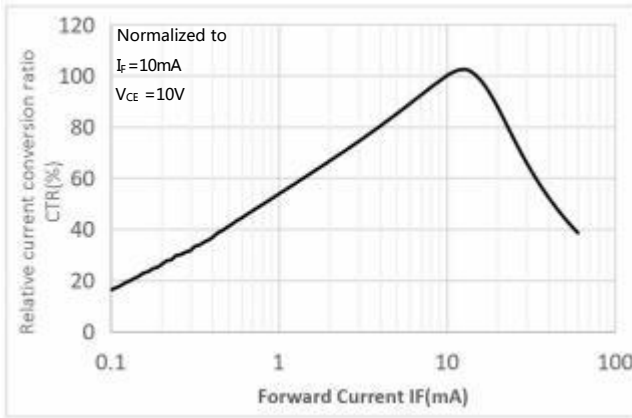


Fig.2 Forward Current vs. Forward Voltage

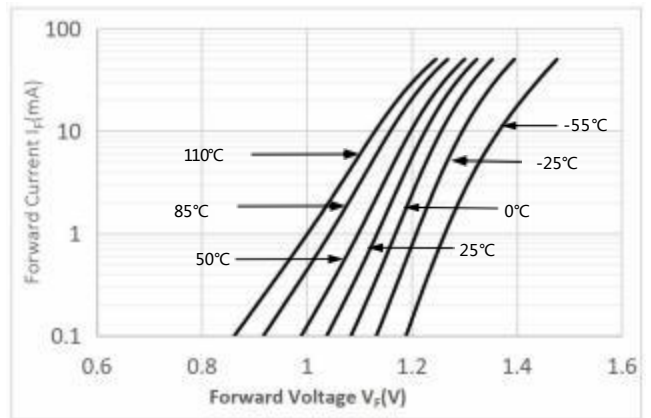


Fig.3 Collector Current vs. Collector-emitter Voltage

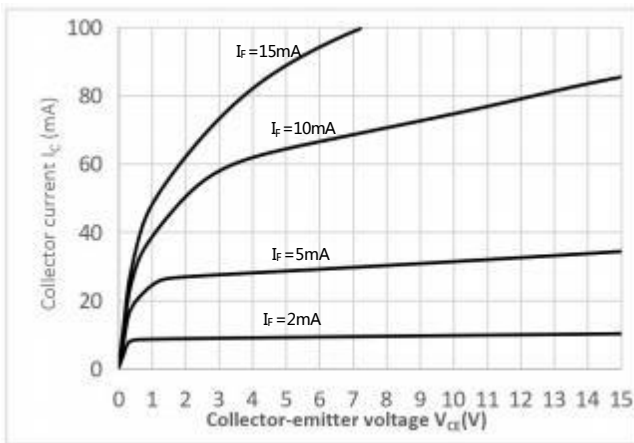


Fig.4 Relative Current Transfer Ratio vs. Ambient Temperature

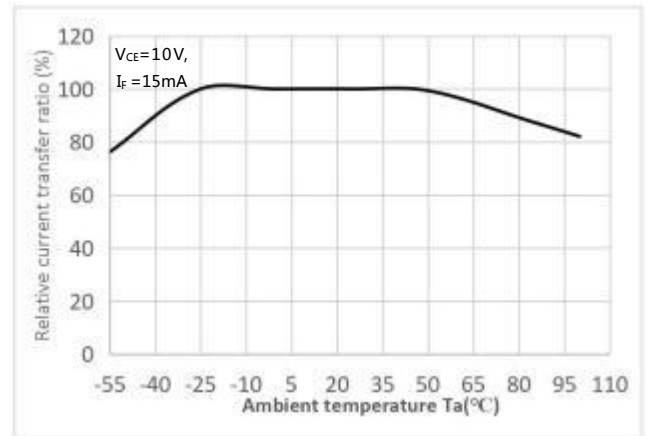


Fig.5 Collector Dark Current vs. Ambient Temperature

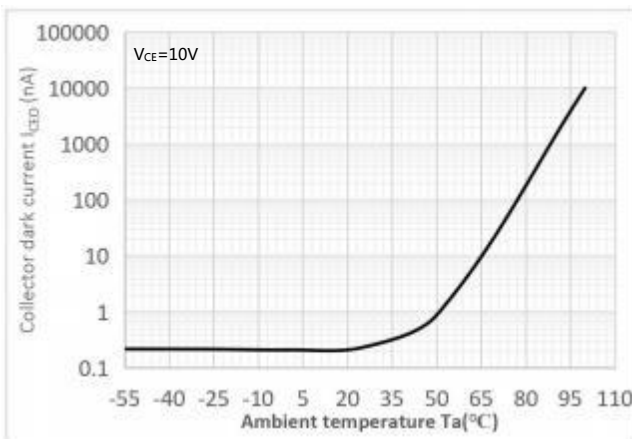


Fig.6 Response Time vs. Load Resistance

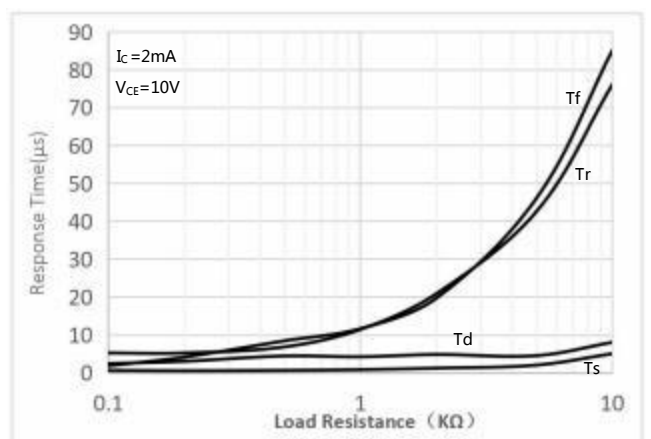


Fig.7 Frequency Response

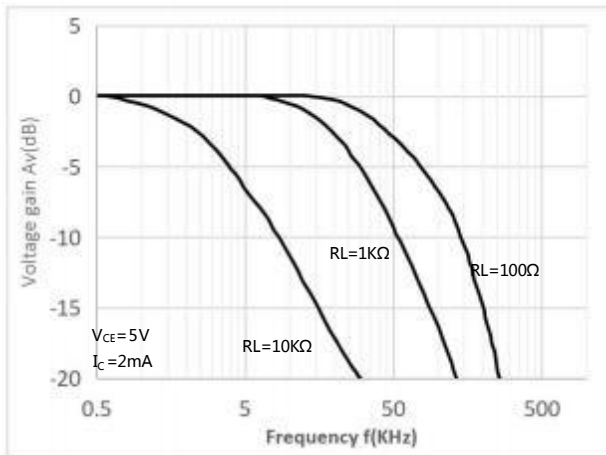


Fig.8 Collector-emitter Saturation Voltage vs Forward Current

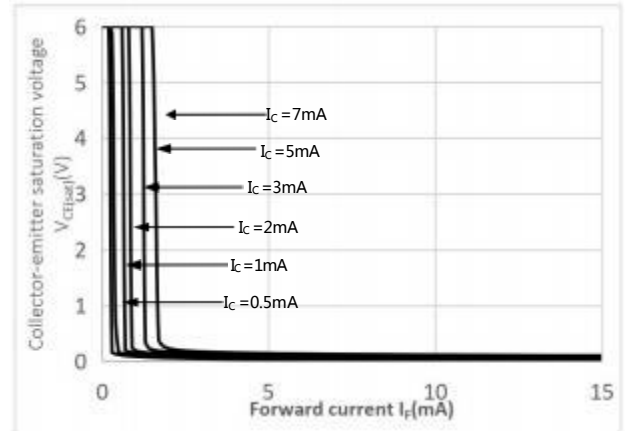
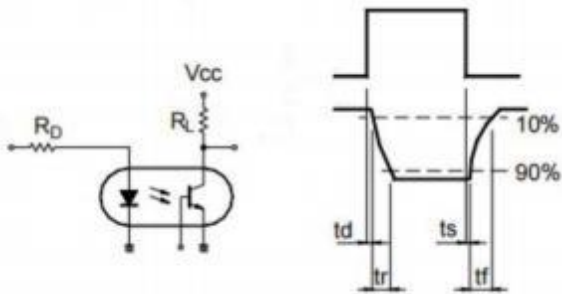
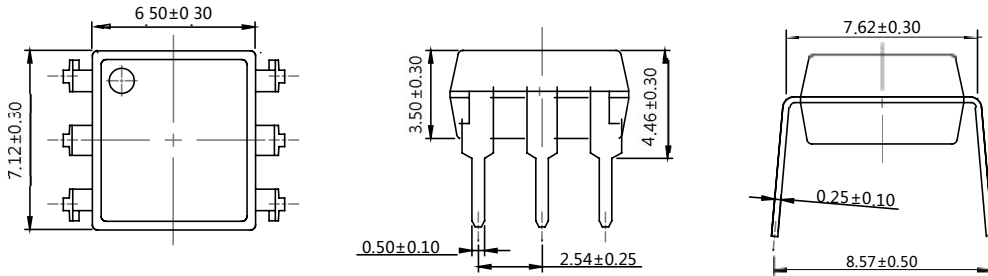


Fig.9 Switching Time Test Circuit & Waveforms

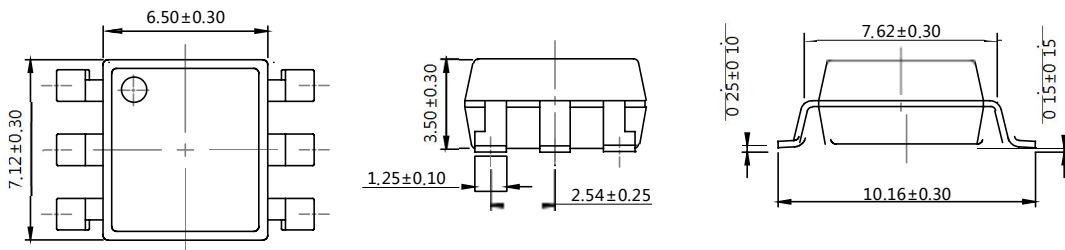


外形尺寸 Outline Dimensions

DIP6



SMD6



单位 Unit: mm

回流焊温度曲线图 Solder Reflow Profile



项目 Item	符号 Symbol	最小值 Min.	最大值 Max.	单位 Unit
预热温度 Preheat Temperature	T_s	150	200	°C
预热时间 Preheat Time	t_s	60	120	s
升温速率 Ramp-Up Rate (T_L to T_P)	-	-	3	°C/s
液相线温度 Liquidus Temperature	T_L	217		°C
时间高于 T_L Time Above T_L	t_L	60	150	s
峰值温度 Peak Temperature	T_P	-	260	°C
T_c 在 $(T_P - 5)$ 和 T_P 之间的时间 Time During Which T_c Is Between $(T_P - 5)$ and T_P	t_p	-	30	s
降温速率 Ramp-down Rate (T_P to T_L)	-	-	6	°C/s

注 Note :

建议在所示的温度和时间条件下进行回流焊，最多不能超过三次；

Reflow soldering is recommended at the temperatures and times shown, no more than three times;

波峰焊温度曲线图 Wave Soldering Profile



手工烙铁焊接 Soldering with hand soldering iron

- A. 手工烙铁焊仅用于产品返修或样品测试；
Hand soldering iron is only used for product rework or sample testing;
- B. 手工烙铁焊要求：温度 360°C ± 5°C，时间 ≤ 3s。
Manual soldering method Temperature: 360°C ± 5°C, within 3s.

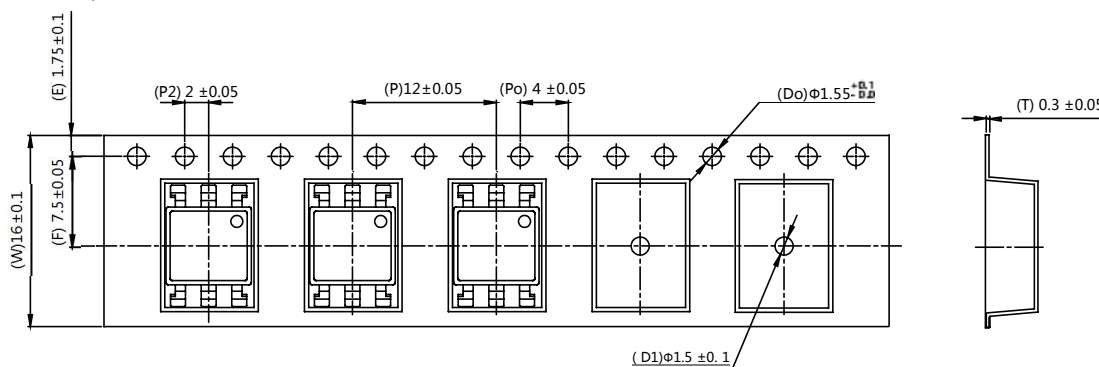
包装 Packing

■ 汇总表 Summary table

封装形式	包装方式	盘数量	盒数量	箱数量	静电袋规格	盒规格	箱(双瓦楞)规格	备注
SMD6	卷盘 ($\phi 330\text{mm}$ 蓝盘)	1000 只/盘	2 盘/盒	10 盒/箱	450*390*0.1mm	340*60*340mm	620*360*365mm	首尾端空至少 200mm
DIP6	管装 (500*12*11mm)	65 只/管	50 管/盒	10 盒/箱	不适用	525*128*56mm	535*275*300mm	每管使用蓝白胶塞, 方向须一致
Package Type	Packing Form	Quantity per Reel	Quantity per Box	Quantity per Carton	Antistatic Bag Specification	Box Specification	Carton Specification	Note
SMD6	Reel ($\phi 330\text{mm}$ Blue)	1000 pcs/reel	2 reels/box	10 boxes/ctn	450*390*0.1mm	340*60*340mm	620*360*365mm	Guard band 200mm min.
DIP6	Tube (500*12*11mm)	65 pcs /tube	50 tubes/box	10 boxes/ctn	NA	525*128*56mm	535*275*300mm	Endplug (blue) and Endplug (white) keep the direction

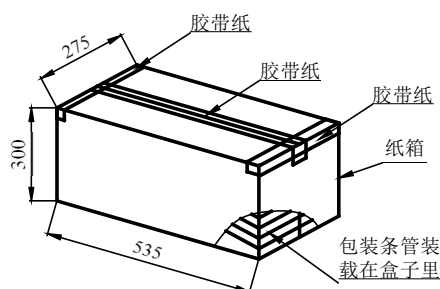
■ 编带包装 Tape & Reel

- 1) 每卷数量：1000 只。
Qty/reel：1000 pcs.
- 2) 每箱数量：20000 只。
Qty/ctn：20000 pcs.
- 3) 内包装：每盒 2 盘。
Inner packing：2 reels/box.
- 4) 示意图 Schematic：



■ 管条包装 Tape & Tube

- 1) 每管数量：65 只。
Qty/Tube：65 pcs.
- 2) 每箱数量：32500 只。
Qty/ctn：32500 pcs.
- 3) 内包装：每盒 50 管。
Inner packing：50 Tube/box.
- 4) 示意图 Schematic：



单位/Unit：mm

注意 Attention

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